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# FPF1003A／FPF1004 IntelliMAX ${ }^{\text {TM }}$ Advanced Load Management Products 

## Features

－ 1.2 V to 5.5 V Input Voltage Operating Range
－Typical $\mathrm{R}_{\mathrm{DS}(\mathrm{ON})}$ ：
－$\quad 30 \mathrm{~m} \Omega$ at $\mathrm{V}_{\mathrm{IN}}=5.5 \mathrm{~V}$
－$\quad 35 \mathrm{~m} \Omega$ at $\mathrm{V}_{\mathrm{IN}}=3.3 \mathrm{~V}$
－ESD Protected：Above 8000 V HBM
－ROHS Compliant

## Applications

－PDA＇s
－Cell Phones
－GPS Devices
－MP3 Players
－Digital Cameras
－Peripheral Ports
－Hot Swap Supplies

## Description

The FPF1003A and FPF1004 are low RDS P－channel MOSFET load switches with controlled turn－on．The input voltage range operates from 1.2 V to 5.5 V to fulfill today＇s ultra－portable device supply requirements． Switch control is accomplished with a logic input（ON） capable of interfacing directly with low－voltage control signal．In FPF1004，a $120 \Omega$ on－chip load resistor is added for output quick discharge when the switch is turned off．

Both FPF1003A and FPF1004 are available in a space－ saving $1.0 \times 1.5 \mathrm{~mm}^{2}$ wafer－level chip－scale package．

## Ordering Information

| Part Number | Top Mark | Switch | Input <br> Buffer | Output <br> Discharge | ON Pin <br> Activity | Package |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| FPF1003A | Q2 | $30 \mathrm{~m} \Omega$ | Schmitt | NA | Active <br> HIGH | $1.0 \times 1.5 \mathrm{~mm}^{2}$ Wafer－Level |
|  | FPF1004 |  |  | $120 \Omega$ | Active <br> HIGH | Chip－Scale Package（WLCSP）， |

## Application Diagram



Figure 1. Typical Application

Block Diagram


Figure 2. Functional Block Diagram

## Pin Configurations



Figure 3. WLCSP Bumps Facing UP


Figure 4. WLCSP Bumps Facing Down

Figure 5. $1.0 \mathrm{~mm} \times 1.5 \mathrm{~mm}$ WLCSP Pin Assignments (Bottom View)

## Pin Definitions

| Pin \# | Name | Description |
| :---: | :---: | :--- |
| A2, B2 | VIN $^{\prime}$ | Input to the power switch and the supply voltage for the IC |
| C2 | ON | ON Control Input |
| A1, B1 | Vout | Output of the power switch |
| C1 | GND | Ground |

## Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

| Symbol | Parameter |  | Min. | Max. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\text {IN }}$ | $\mathrm{V}_{\text {IN }}, \mathrm{V}_{\text {OUt }}, \mathrm{ON}$ to GND |  | -0.3 | 6.0 | V |
| Isw | Maximum Continuous Switch Current |  |  | 2.0 | A |
| $\mathrm{P}_{\mathrm{D}}$ | Power Dissipation at $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}^{(1)}$ |  |  | 1.2 | W |
| $\mathrm{T}_{\text {STG }}$ | Storage Junction Temperature |  | -65 | +150 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\mathrm{A}}$ | Operating Temperature Range |  | -40 | +125 | ${ }^{\circ} \mathrm{C}$ |
| $\Theta_{J A}$ | Thermal Resistance, Junction-to-Ambient |  |  | 85 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| ESD | Electrostatic Discharge Capability | Human Body Model, JESD22-A114 | 5500 |  | V |
|  |  | Charged Device Model, JESD22-C101 | 1500 |  |  |

## Note:

1. Package power dissipation on one square inch pad, 2 oz .

## Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to Absolute Maximum Ratings.

| Symbol | Parameter | Min. | Max. | Unit |
| :---: | :--- | :---: | :---: | :---: |
| $\mathrm{V}_{\mathrm{IN}}$ | Supply Voltage | 1.2 | 5.5 | V |
| $\mathrm{~T}_{\mathrm{A}}$ | Ambient Operating Temperature | -40 | +85 | ${ }^{\circ} \mathrm{C}$ |

## Electrical Characteristics

Unless otherwise noted, $\mathrm{V}_{\mathbb{I N}}=1.2$ to $5.0 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=-40$ to $+85^{\circ} \mathrm{C}$; typical values are at $\mathrm{V}_{\mathbb{I N}}=3.3 \mathrm{~V}$ and $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.

| Symbol | Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Basic Operation |  |  |  |  |  |  |
| $\mathrm{V}_{\text {IN }}$ | Supply Voltage |  | 1.2 |  | 5.5 | V |
| $\mathrm{I}_{\text {Q(OFF) }}$ | Off Supply Current | $\mathrm{V}_{\text {ON }}=\mathrm{GND}$, OUT=Open |  |  | 1 | $\mu \mathrm{A}$ |
| ISD | Shutdown Current | $\mathrm{V}_{\text {ON }}=\mathrm{GND}, \mathrm{V}_{\text {OUT }}=0$ at $\mathrm{V}_{\text {IN }}=5.5, \mathrm{~T}_{\mathrm{A}}=85^{\circ} \mathrm{C}$ |  |  | 1 | $\mu \mathrm{A}$ |
|  |  | $\mathrm{V}_{\text {ON }}=\mathrm{GND}$, $\mathrm{V}_{\text {OUT }}=0$ at $\mathrm{V}_{\text {IN }}=3.3, \mathrm{~T}_{\mathrm{A}}=85^{\circ} \mathrm{C}$ |  | 10 | 100 | nA |
| $\mathrm{I}_{\mathrm{Q}}$ | Quiescent Current | $\mathrm{I}_{\text {OUT }}=0 \mathrm{~mA}, \mathrm{~V}_{\text {IN }}=\mathrm{V}_{\text {ON }}$ |  |  | 1 | $\mu \mathrm{A}$ |
| Ron | On-Resistance | $\mathrm{V}_{\text {IN }}=5.5 \mathrm{~V}$, l lout $=1 \mathrm{~A}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | 20 | 30 | $\mathrm{m} \Omega$ |
|  |  | $\mathrm{V}_{\text {IN }}=3.3 \mathrm{~V}$, $\mathrm{l}_{\text {OUT }}=1 \mathrm{~A}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | 25 | 35 |  |
|  |  | $\mathrm{V}_{\text {IN }}=1.5 \mathrm{~V}$, $\mathrm{l}_{\text {OUT }}=1 \mathrm{~A}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | 50 | 75 |  |
|  |  | $\mathrm{V}_{\text {IN }}=1.2 \mathrm{~V}$, $\mathrm{l}_{\text {OUT }}=1 \mathrm{~A}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | 95 | 150 |  |
|  |  | $\mathrm{V}_{\text {IN }}=3.3 \mathrm{~V}$, $\mathrm{l}_{\text {OUT }}=1 \mathrm{~A}, \mathrm{~T}_{\mathrm{A}}=85^{\circ} \mathrm{C}$ |  | 30 | 42 |  |
|  |  | $\mathrm{V}_{\text {IN }}=3.3 \mathrm{~V}$, lout $=1 \mathrm{~A}, \mathrm{~T}_{\mathrm{A}}=40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$ | 12 |  | 42 |  |
| $\mathrm{R}_{\text {PD }}$ | Output Pull-Down Resistance | $\mathrm{V}_{\mathrm{IN}}=3.3 \mathrm{~V}, \mathrm{~V}_{\mathrm{ON}}=0 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$, FPF1004 |  | 75 | 120 | $\Omega$ |
| $\mathrm{V}_{\mathrm{IH}}$ | ON Input Logic High Voltage | $\mathrm{V}_{\text {IN }}=1.2 \mathrm{~V}$ to 5.5 V | 2 |  |  | V |
|  |  | $\mathrm{V}_{\text {IN }}=1.2 \mathrm{~V}$ | 0.8 |  |  |  |
| VIL | ON Input Logic Low Voltage | $\mathrm{V}_{\text {IN }}=2.7 \mathrm{~V}$ to 5.5 V |  |  | 0.8 | V |
|  |  | $\mathrm{V}_{\mathrm{IN}}=1.2 \mathrm{~V}$ |  |  | 0.35 |  |
| Ion | ON Input Leakage | $\mathrm{V}_{\text {ON }}=\mathrm{V}_{\text {IN }}$ or GND |  |  | 1 | $\mu \mathrm{A}$ |
| Dynamic Characteristics |  |  |  |  |  |  |
| ton | Turn-On Time | $\begin{aligned} & \mathrm{V}_{\mathbb{I N}}=3.3 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=500 \Omega, \mathrm{C}_{\mathrm{L}}=0.1 \mu \mathrm{~F}, \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \end{aligned}$ |  | 13 |  | $\mu \mathrm{s}$ |
| toff | Turn-Off Time | $\mathrm{V}_{\mathrm{IN}}=3.3 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=500 \Omega, \mathrm{C}_{\mathrm{L}}=0.1 \mu \mathrm{~F}$, $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$, FPF1003A |  | 45 |  | $\mu \mathrm{s}$ |
|  |  | $\begin{aligned} & \mathrm{V}_{\mathrm{IN}}=3.3 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=500 \Omega, \mathrm{C}_{\mathrm{L}}=0.1 \mu \mathrm{~F}, \\ & \mathrm{R}_{\mathrm{L}_{-} \mathrm{CHIP}}=120 \Omega, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \text { FPF } 1004 \end{aligned}$ |  | 15 |  |  |
| $t_{R}$ | Vout Rise Time | $\begin{aligned} & \mathrm{V}_{\mathrm{IN}}=3.3 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=500 \Omega, \mathrm{C}_{\mathrm{L}}=0.1 \mu \mathrm{~F}, \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \end{aligned}$ |  | 13 |  | $\mu \mathrm{s}$ |
| $t_{\text {F }}$ | Vout Fall Time | $\begin{aligned} & \mathrm{V}_{\mathrm{IN}}=3.3 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=500 \Omega, \mathrm{C}_{\mathrm{L}}=0.1 \mu \mathrm{~F}, \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{FPF} 1003 \mathrm{~A} \end{aligned}$ |  | 113 |  | $\mu \mathrm{s}$ |
|  |  | $\mathrm{V}_{\mathrm{IN}^{\prime}}=3.3 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=500 \Omega, \mathrm{C}_{\mathrm{L}}=0.1 \mu \mathrm{~F}$, $\mathrm{R}_{\mathrm{L}-\mathrm{CHIP}}=120 \Omega, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$, FPF 1004 |  | 10 |  |  |

## Typical Performance Characteristics



Figure 6. Quiescent Current vs. $\mathrm{V}_{\mathrm{IN}}$


Figure 8. Quiescent Current vs. Temperature


Figure 10. Iswitch-off Current vs. Temperature


Figure 7. ON Threshold vs. $\mathrm{V}_{\mathrm{IN}}$


Figure 9. Quiescent Current (OFF) vs. Temperature


Figure 11. Iswitch-off Current vs. $\mathrm{V}_{\mathrm{IN}}$

Typical Performance Characteristics


Figure 12. Row vs. $\mathrm{V}_{\mathrm{IN}}$


Figure 14. $t_{o n} / t_{\text {off }}$ vs. Temperature


Figure 16. FPF1003A ton Response


Figure 13. Ron vs. Temperature


Figure 15. $t_{R} / t_{F}$ vs. Temperature


Figure 17. FPF1003A toff Response

## Typical Performance Characteristics



Figure 18. FPF1003A ton Response


Figure 20. FPF1004 ton Response


Figure 22. FPF1004 ton Response


Figure 19. FPF1003A toff Response


Figure 21. FPF1004 toff Response


Figure 23. FPF1004 toff Response

## Description of Operation

## Input Capacitor

FPF1003A and FPF1004 are low-Rds(on) P-channel load switches with controlled turn-on. The core of each device is a $30 \mathrm{~m} \Omega$ P-Channel MOSFET and a controller capable of functioning over an input operating range of
1.2 to 5.5 V . Switch control is accomplished with a logic input (ON) capable of interfacing directly with lowvoltage control signal. In FPF1004, a $120 \Omega$ on-chip load resistor is added for output quick discharge when the switch is turned off.

## Application Information



Figure 24. Typical Application

## Input Capacitor

To limit the voltage drop on the input supply caused by transient inrush currents when the switch turns on into a discharged load capacitor or short-circuit, a capacitor needs to be placed between $\mathrm{V}_{\mathrm{IN}}$ and GND. A $0.1 \mu \mathrm{~F}$ ceramic capacitor, $\mathrm{C}_{\mathrm{IN}_{\mathrm{N}}}$, must be placed close to the $\mathrm{V}_{\mathrm{IN}}$ pin . A higher value of $\mathrm{C}_{\mathrm{IN}}$ can be used to further reduce the voltage drop experienced as the switch is turned on into a large capacitive load.

## Output Capacitor

A $0.1 \mu \mathrm{~F}$ capacitor, $\mathrm{C}_{\text {out }}$, should be placed between VOUT and GND. This capacitor prevents parasitic board inductance from forcing $V_{\text {Out }}$ below GND when the switch turns off. Due to the integral body diode in the

PMOS switch, a $\mathrm{C}_{\mathbb{N}}$ greater than $\mathrm{C}_{\text {OUt }}$ is recommended. A Cout greater than $\mathrm{C}_{\text {IN }}$ can cause $\mathrm{V}_{\text {out }}$ to exceed $\mathrm{V}_{\text {IN }}$ when the system supply is removed. This could result in current flow through the body diode from $\mathrm{V}_{\text {OUT }}$ to $\mathrm{V}_{\text {IN }}$.

## Board Layout

For best performance, all traces should be as short as possible. To be most effective, the input and output capacitors should be placed close to the device to minimize the effects that parasitic trace inductances may have on normal and short-circuit operation. Using wide traces for $\mathrm{V}_{\text {IN }}$, Vout, and GND minimizes the parasitic electrical effects and case-to-ambient thermal impedance.

## Physical Dimensions



## NOTES:

A. NO JEDEC REGISTRATION APPLIES.

bOttom View
B. DIMENSIONS ARE IN MILLIMETERS.
C. DIMENSIONS AND TOLERANCE PER ASMEY14.5M, 1994.
D. DATUM C IS DEFINED BY THE SPHERICAL CROWNS OF THE BALLS.
E. PACKAGE NOMINAL HEIGHT IS 582 MICRONS $\pm 43$ MICRONS ( $539-625$ MICRONS).
F. FOR DIMENSIONS D, E, X, AND Y SEE PRODUCT DATASHEET.
G. DRAWING FILNAME: MKT-UC006AFrev2.

Figure 25. $1.0 \times 1.5 \mathrm{~mm}^{2}$ Wafer-Level Chip-Scale Package (WLCSP)
Product-Specific Dimensions

| Product | D | E | X | Y |
| :---: | :---: | :---: | :---: | :---: |
| FPF1003A | $1480 \mu \mathrm{~m} \pm 30 \mu \mathrm{~m}$ | $980 \mu \mathrm{~m} \pm 30 \mu \mathrm{~m}$ | $240 \mu \mathrm{~m}$ | $240 \mu \mathrm{~m}$ |
| FPF1004 | $1480 \mu \mathrm{~m} \pm 30 \mu \mathrm{~m}$ | $980 \mu \mathrm{~m} \pm 30 \mu \mathrm{~m}$ | $240 \mu \mathrm{~m}$ | $240 \mu \mathrm{~m}$ |

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